

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	751	@ad<="20040325" and 'high voltage' same 'ESD' with 'protection'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:29
L2	1569	@ad<="20040325" and (257/355). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:26
L3	630	@ad<="20040325" and (257/356). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:26
L4	465	@ad<="20040325" and (257/357). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:26
L5	306	@ad<="20040325" and (257/358). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:26
L6	235	@ad<="20040325" and (257/359). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:26
L8	460	@ad<="20040325" and (257/362). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:26
L9	401	@ad<="20040325" and (257/363). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:26
L11	400	@ad<="20040325" and (438/309). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:27
L12	801	@ad<="20040325" and (257/360). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:27
L13	273	@ad<="20040325" and (257/361). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:27

L14	172	@ad<="20040325" and 'high voltage' same 'ESD' with 'protection' and 'PNP' with 'transistor'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:48
L15	28	@ad<="20040325" and 'Bipolar ESD protection'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 12:40
L16	1	"6720625".PN.	USPAT; USOCR	OR	ON	2005/07/26 11:35
L17	1	"5850095".PN.	USPAT; USOCR	OR	ON	2005/07/26 11:36
L18	1	"6472286".PN.	USPAT; USOCR	OR	ON	2005/07/26 11:36
L19	1	"5850095".PN.	USPAT; USOCR	OR	ON	2005/07/26 11:37
L20	1	"5528189".PN.	USPAT; USOCR	OR	ON	2005/07/26 11:37
L21	1	"6008524".PN.	USPAT; USOCR	OR	ON	2005/07/26 11:38
L22	601	@ad<="20040325" and 'Bipolar' with 'ESD' with 'protection'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:44
L23	148	@ad<="20040325" and 'Bipolar' with 'ESD' with 'protection' and 'p-well' and 'n-well'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 11:45
L24	1	"20040016992".PN.	US-PGPUB	OR	ON	2005/07/26 11:45
L25	1	"6365939".PN.	USPAT; USOCR	OR	ON	2005/07/26 11:45
L26	1	"5949109".PN.	USPAT; USOCR	OR	ON	2005/07/26 11:46
L27	482	@ad<="20040325" and 'PNP transistor' and 'ESD' with 'protection'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 12:39
L28	123	@ad<="20040325" and 'electrostatic discharge' same 'thyristors'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 12:26
L29	1	"5717559".PN.	USPAT; USOCR	OR	ON	2005/07/26 12:32
L30	430	@ad<="20040325" and 'NPN transistor' same 'ESD'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 12:39

L31	215	@ad<="20040325" and 'NPN transistor' same 'ESD' and 'high voltage'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 12:40
L32	1097	@ad<="20040325" and 'Bipolar transistor' and 'ESD protection'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 12:40
L33	1	"6353237".PN.	USPAT; USOCR	OR	ON	2005/07/26 12:43
L34	1	"5012317".PN.	USPAT; USOCR	OR	ON	2005/07/26 12:44
L35	1	"5614755".PN.	USPAT; USOCR	OR	ON	2005/07/26 13:38
L36	1	"5478764".PN.	USPAT; USOCR	OR	ON	2005/07/26 13:38